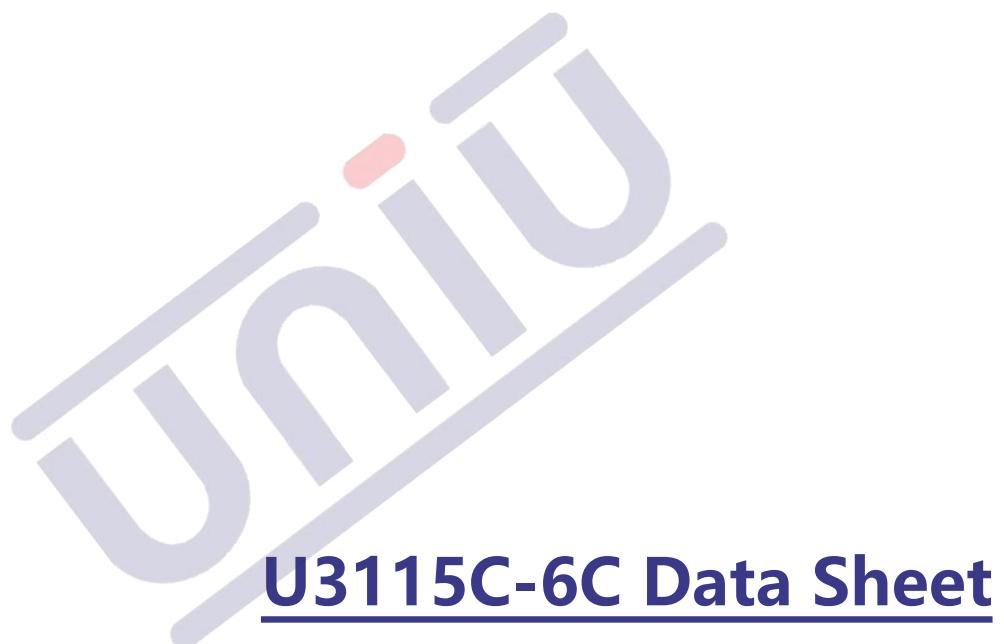




ZHEJIANG UNIU-NE Technology CO., LTD

浙江宇力微新能源科技有限公司



V 1.2

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Half-bridge of power MOSFET/IGBT Drive

General Description

The U3115C/U3116C Fully operated to +350V is high voltage, high speed power MOSFET and IGBT driver with dependent high and low side referenced output channels.

The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 350 volts.

Product Summary

| | |
|-----------------------------|-------------|
| V _{OFFSET} | 350V |
| I _{O+/-} | 1.0A / 1.2A |
| V _{CCon/off(typ.)} | 4.5V & 4.2V |
| V _{Bon/off} (typ.) | 5V & 4.9V |
| t _{on/off} (typ.) | 450 & 150ns |
| Deadtime (typ.) | 300 ns |
| Work Tem | -40 ~150 °C |

Product information

| Base Part Number | Package Type | Standard OUT | | V _{OFFSET} | Logic Control |
|------------------|--------------|-----------------|-----------------|---------------------|---------------|
| | | I _{O+} | I _{O-} | | |
| U3115C | SOP8 | 1.0A | 1.2A | 350V | HIN & LIN |
| U3116C | SOP8 | 1.0A | 1.2A | 350V | HIN & LIN |

Note: (1) When using internal diode bootstrap power supply, please match the capacitor and MOS, and fully test and verify

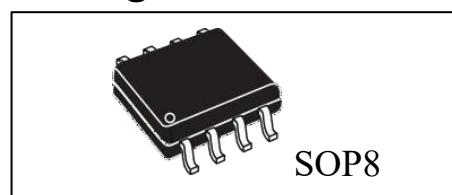
Key Features

- Integrated bootstrap Diode⁽¹⁾
- Floating channel designed for bootstrap operation
- Fully operational to +350V
- Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 5 to 20V
- Undervoltage lockout
- 3.3V, 5V and 15V input logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels

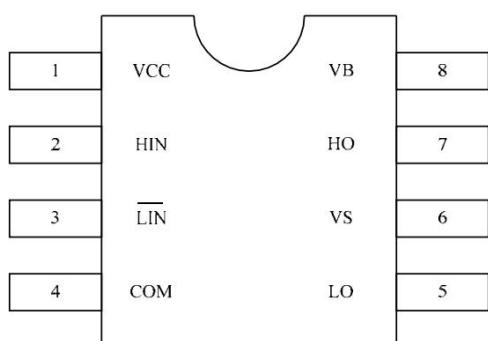
Applications

- Home appliances
- Industrial applications and drives
- Motor drivers
- DC- AC Converter, PMDC and PMAC motors
- Induction heating
- HVAC

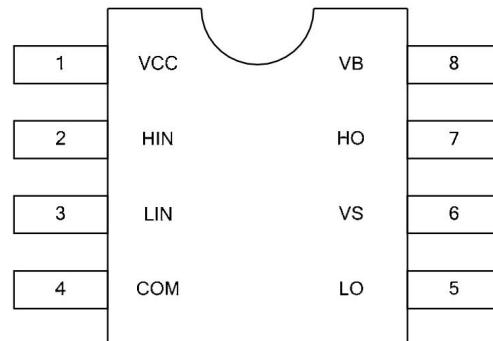
Packages



Pin Assignments



U3115C

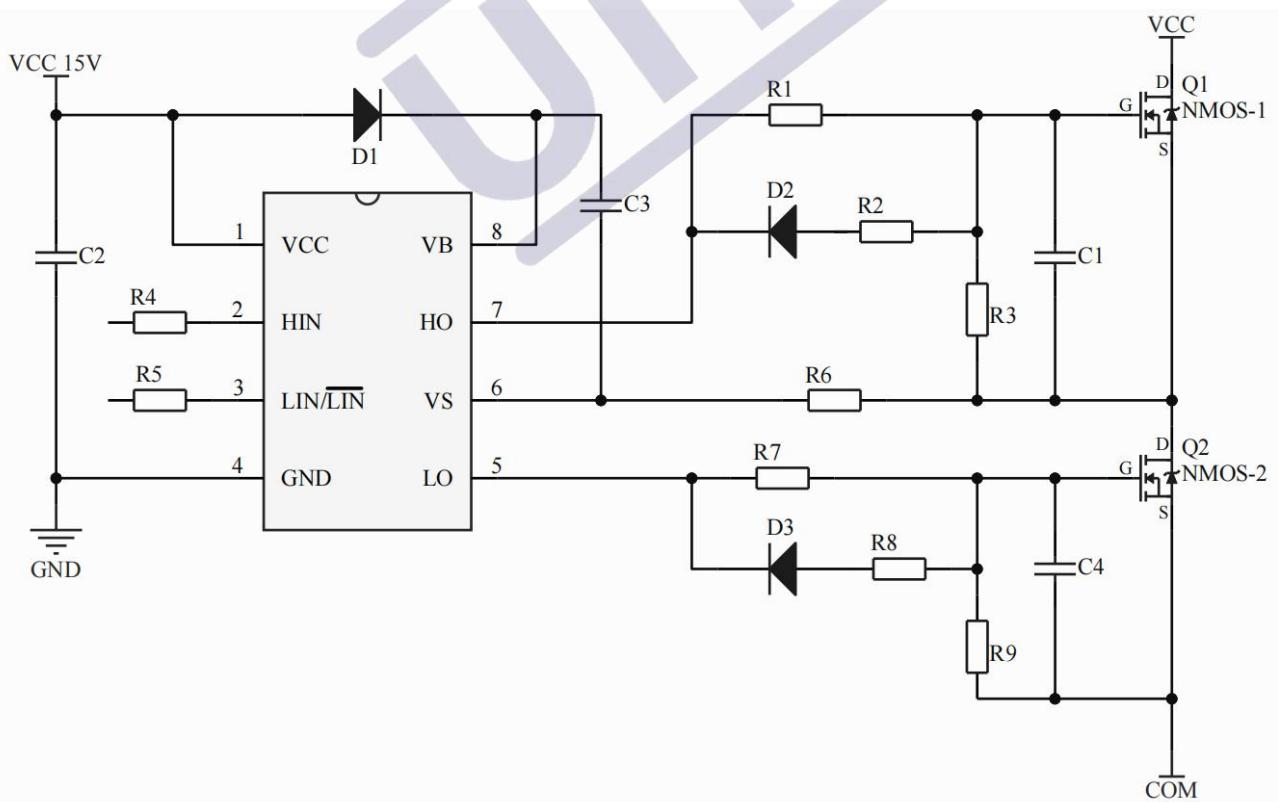
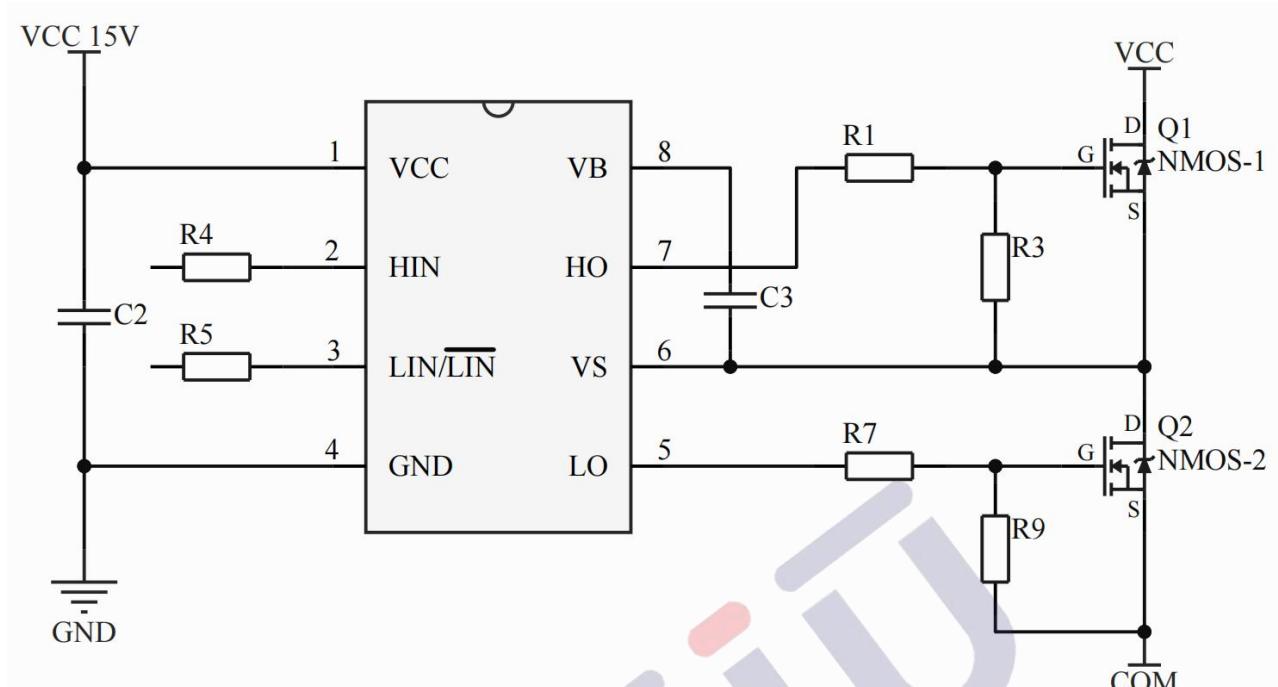


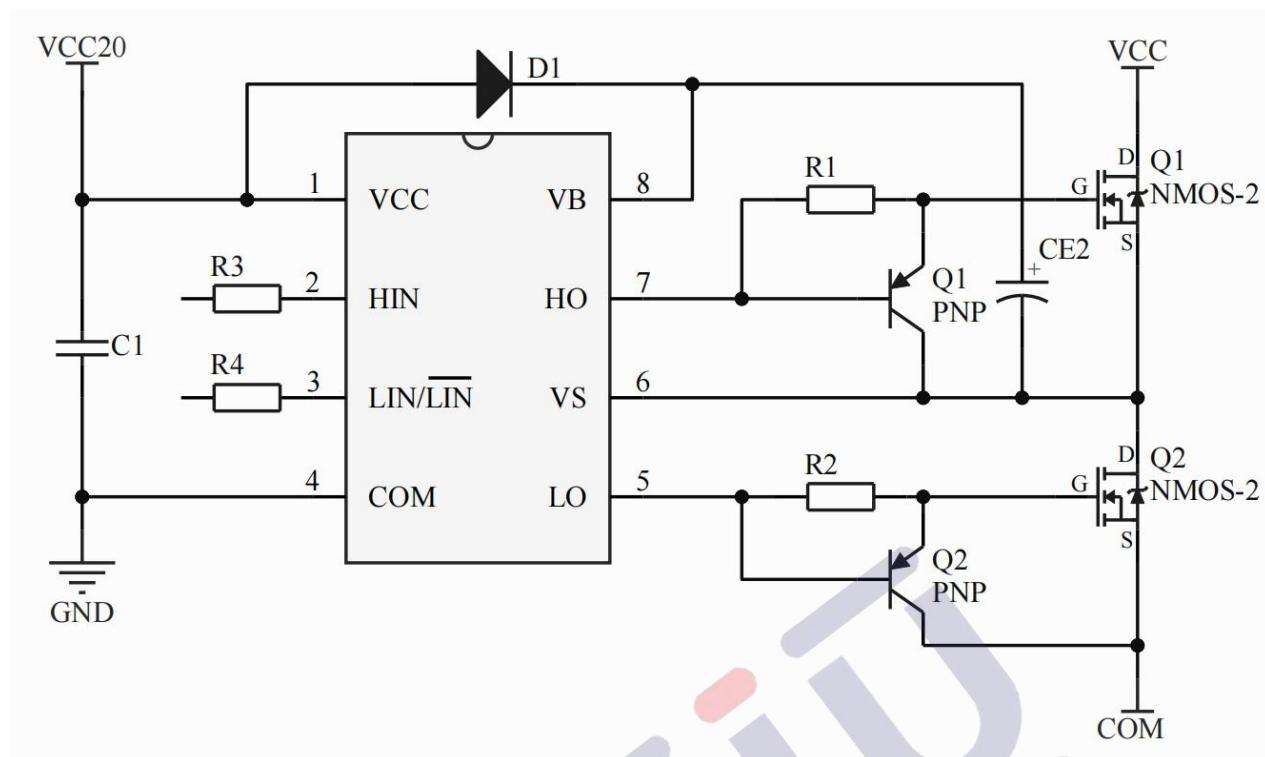
U3116C

Pin Function

| Number | Symbol | Type | Description |
|--------|------------|------|--|
| 1 | VCC | P | Low side and logic fixed supply |
| 2 | HIN | I | High side driver logic input (active high) |
| 3 | LIN | I | Low side driver logic input (active high) |
| | <u>LIN</u> | I | Low side driver logic input (active low) |
| 4 | COM | P | Low side return |
| 5 | LO | O | Low side gate drive output |
| 6 | VS | P | High side floating supply return |
| 7 | HO | O | High side gate drive output |
| 8 | VB | P | High side floating supply |

Typical Connection





Much Big POWER application

Note: The above circuits and parameters are for reference only. The actual application circuit should be designed with the measured results in setting the parameters

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

| Symbol | Definition | Min. | Max. | Units |
|--------|--|--------|---------|-------|
| VB | High side floating absolute voltage | -0.3 | 365 | V |
| VS | High side floating supply offset voltage | VB-15 | VB+0.3 | |
| VHO | High side floating output voltage | VS-0.3 | VB+0.3 | |
| VLO | Low side output voltage | -0.3 | Vcc+0.3 | |
| Vcc | Low side and logic fixed supply voltage | -0.3 | 20 | |
| VIN | Logic input voltage (HIN & LIN) | -0.3 | Vcc+0.3 | |
| dVS/dt | Allowable offset supply voltage transient | - | 55 | V/ns |
| PD | Package power dissipation @ TA≤+25°C , SOIC-8 | - | 0.625 | W |
| RthJA | Thermal resistance, junction to ambient , SOIC-8 | - | 200 | °C/W |
| TJ | Junction temperature | -35 | 150 | °C |
| TS | Storage temperature | -55 | 175 | |
| TL | Lead temperature (soldering, 10 seconds) | - | 300 | |

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The VS offset rating is tested with all supplies biased at 15V differential.

| Symbol | Definition | Min. | Max. | Units |
|--------|--|--------|---------|-------|
| VB | High side floating supply absolute voltage | VS + 5 | VS + 20 | V |
| VS | High side floating supply offset voltage | -5 | 350 | |
| VHO | High side floating output voltage | VS | VB | |
| VLO | Low side output voltage | 0 | VCC | |
| VCC | Low side and logic fixed supply voltage | 5 | 20 | |
| VIN | Logic input voltage (HIN&LIN) | 0 | VCC | |
| TA | Ambient temperature | -40 | 150 | °C |

Dynamic Electrical Characteristics

$V_{BIAS}(VCC, VBS) = 12V$, Typical Connection Figure 1 and $TA = 25^\circ C$ unless otherwise specified.

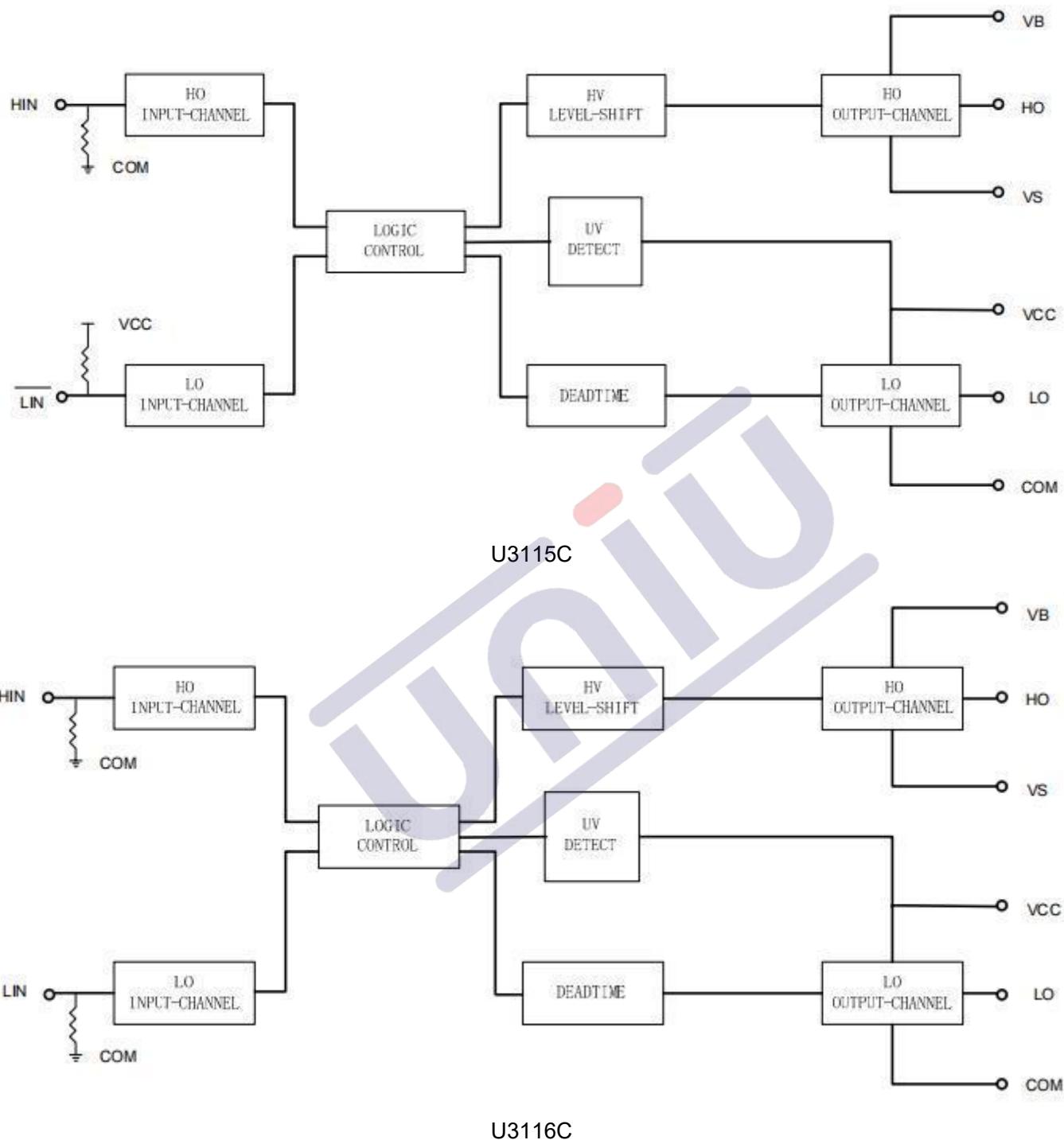
| Symbol | Definition | Min. | Typ. | Max. | Units | Test Conditions |
|--------|--|------|------|------|-------|-----------------|
| ton | Turn-on propagation delay | — | 450 | 550 | ns | VS = 0V |
| toff | Turn-off propagation delay | — | 150 | 250 | | VS = 90V |
| tr | Turn-on rise time | — | 50 | 75 | | |
| tf | Turn-off fall time | — | 25 | 50 | | |
| DT | Deadtime, LS turn-off to HS turn- on & HS turn-on to LS turn-off | 240 | 300 | 360 | | |
| MT | Delay matching, HS & LS turn-on/off | — | — | 60 | | |

Electrical Characteristic

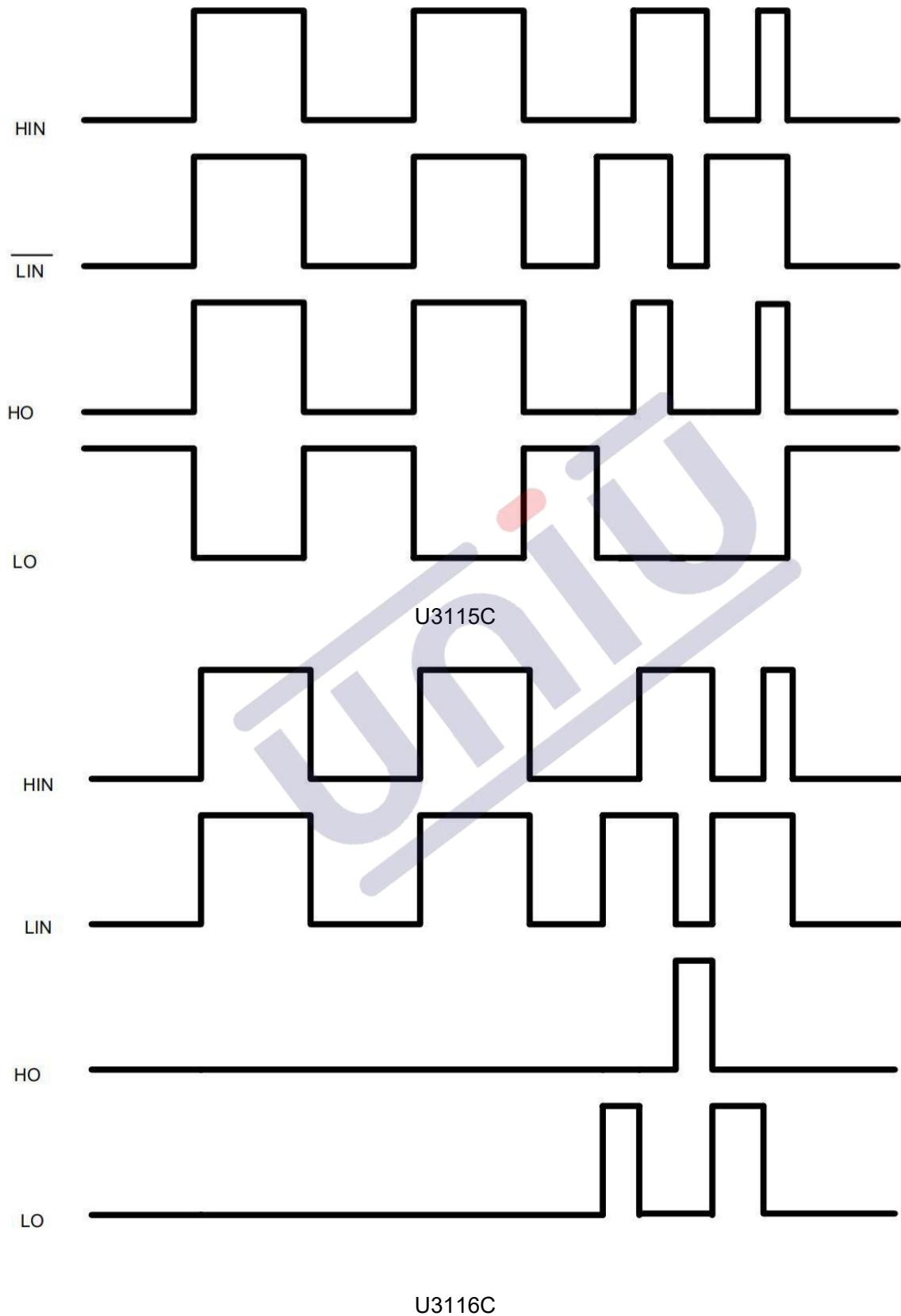
$V_{CC} = V_{BS} = V_{BIAS} = 15V$, $T_A = 25^\circ C$, unless otherwise specified.

| Symbol | Definition | Min. | Typ. | Max. | Units | Test Conditions |
|--|---|------|------|------|-------|-----------------------------------|
| Low Side Power Supply Characteristics | | | | | | |
| V_{CCUV+} | VCC supply under-voltage positive going threshold | — | 4.5 | 5.4 | V | |
| V_{CCUV-} | VCC supply under-voltage negative going threshold | — | 4.2 | 5.1 | | |
| V_{CCHYS} | VCC supply under-voltage lockout hysteresis | - | 0.3 | — | | |
| High Side Floating Power Supply Characteristics | | | | | | |
| V_{BSUV+} | High side VBS supply under-voltage positive going threshold | — | 5.0 | 5.6 | V | |
| V_{BSUV-} | High side VBS supply under-voltage negative going threshold | — | 4.9 | 5.5 | | |
| V_{BSUVHS} | High side VBS supply under-voltage lockout hysteresis | - | 0.1 | — | | |
| IQCC | Quiescent VCC supply current | — | 70 | — | uA | $V_{IN} = 0V \text{ or } 5V$ |
| IQBS | Quiescent VBS supply current | — | 20 | — | | $V_{IN} = 0V \text{ or } 5V$ |
| ILK | Offset supply leakage current | - | - | 30 | | $VB = VS = 90V$ |
| VIH | Logic "1" (HO) & Logic "0" (LO) input voltage | 2.5 | - | - | V | $VCC = 5V \text{ to } 20V$ |
| VIL | Logic "0" (HO) & Logic "1" (LO) input voltage | - | 1.6 | - | | $VCC = 5V \text{ to } 20V$ |
| IIN+ | Logic "1" input bias current | - | 10 | - | uA | $V_{IN} = 5V \text{ L}_{IN} = 0V$ |
| IIN- | Logic "0" input bias current | - | - | 1 | | $V_{IN} = 5V \text{ L}_{IN} = 0V$ |
| VOH | High level output voltage, $V_{BIAS} - VO$ | - | - | 100 | mV | $I_o = 0A$ |
| VOL | Low level output voltage, VO | - | - | 100 | | $I_o = 0A$ |
| IO+ | Output high short circuit pulsed current | - | 1000 | - | mA | $VO = 0V, V_{IN} = V_{IH}$ |
| IO- | Output low short circuit pulsed current | - | 1200 | - | | $PW \leq 10 \mu s$ |

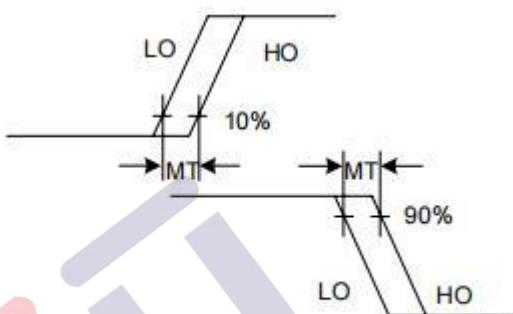
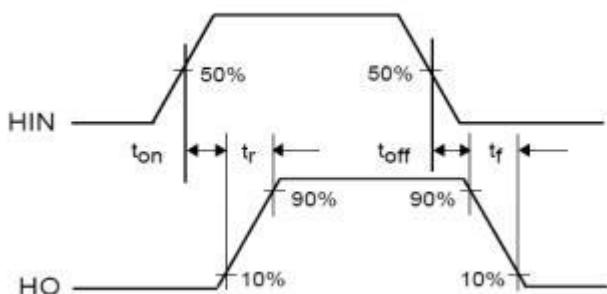
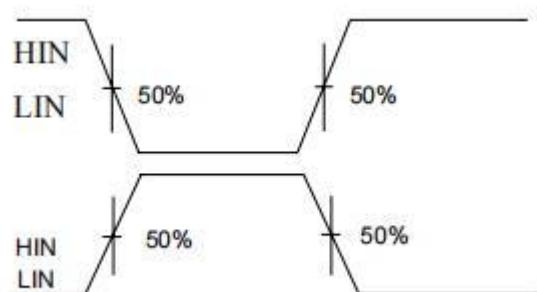
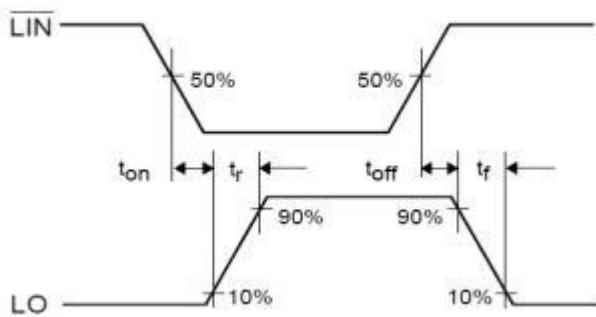
Block Diagram



Time waveform

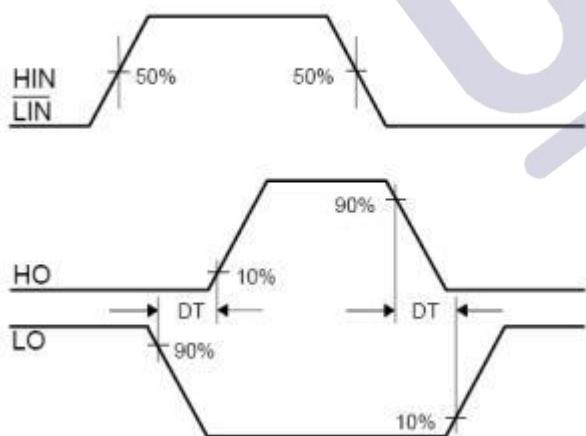


Time waveform



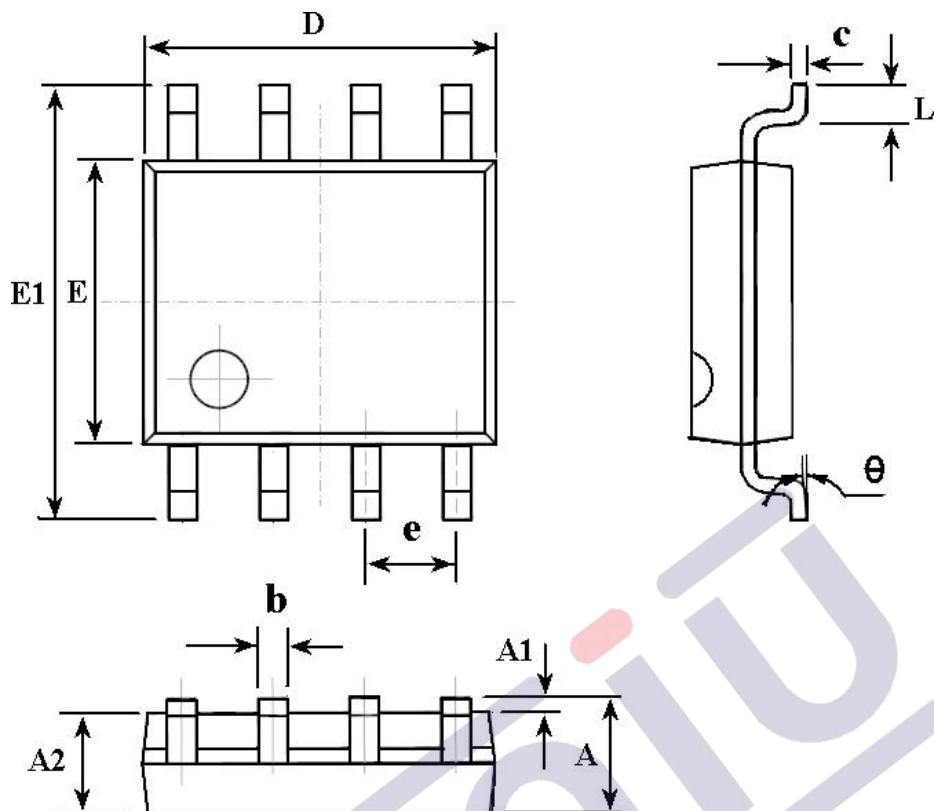
Switching Time Waveform Definitions

Delay matching time Definitions



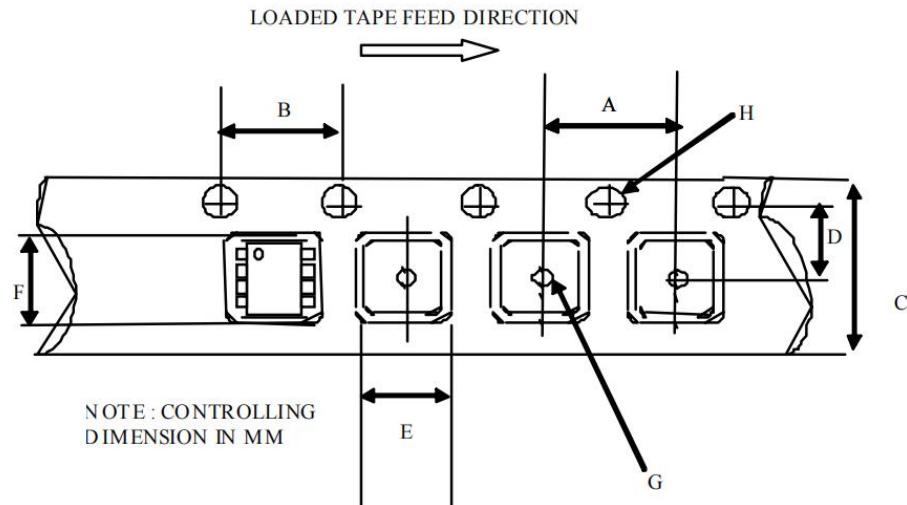
Deadtime Waveform Definitions

Packaging information SOP8



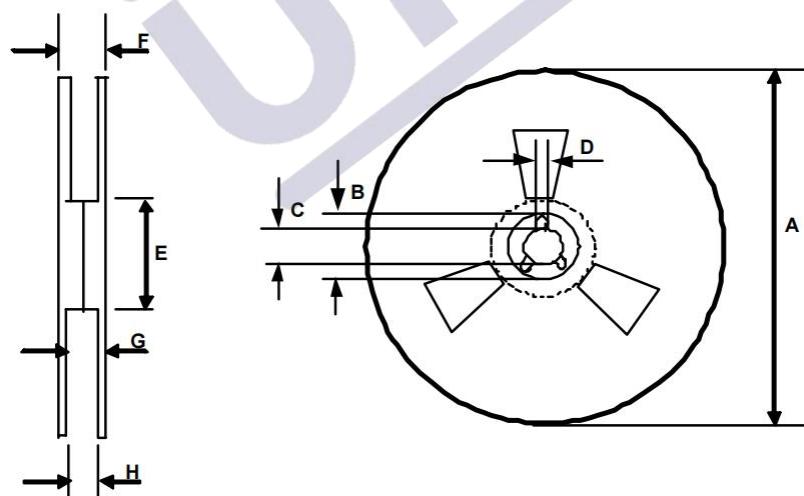
| Symbol | Dimensions In Millimeters | |
|--------|---------------------------|-------|
| | Min | Max |
| A | 1.350 | 1.750 |
| A1 | 0.100 | 0.250 |
| A2 | 1.350 | 1.550 |
| b | 0.330 | 0.510 |
| c | 0.170 | 0.250 |
| D | 4.700 | 5.100 |
| E | 3.800 | 4.000 |
| E1 | 5.800 | 6.200 |
| e | 1.270(BSC) | |
| L | 0.400 | 1.270 |
| θ | 0° | 8° |

Tape & Reel SOP8



CARRIER TAPE DIMENSION FOR 8SOP

| Code | Metric | | Imperial | |
|------|--------|-------|----------|-------|
| | Min | Max | Min | Max |
| A | 7.90 | 8.10 | 0.311 | 0.318 |
| B | 3.90 | 4.10 | 0.153 | 0.161 |
| C | 11.70 | 12.30 | 0.46 | 0.484 |
| D | 5.45 | 5.55 | 0.214 | 0.218 |
| E | 6.30 | 6.50 | 0.248 | 0.255 |
| F | 5.10 | 5.30 | 0.200 | 0.208 |
| G | 1.50 | n/a | 0.059 | n/a |
| H | 1.50 | 1.60 | 0.059 | 0.062 |



REEL DIMENSIONS FOR 8SOP

| Code | Metric | | Imperial | |
|------|--------|--------|----------|--------|
| | Min | Max | Min | Max |
| A | 329.60 | 330.25 | 12.976 | 13.001 |
| B | 20.95 | 21.45 | 0.824 | 0.844 |
| C | 12.80 | 13.20 | 0.503 | 0.519 |
| D | 1.95 | 2.45 | 0.767 | 0.096 |
| E | 98.00 | 102.00 | 3.858 | 4.015 |
| F | n/a | 18.40 | n/a | 0.724 |
| G | 14.50 | 17.10 | 0.570 | 0.673 |
| H | 12.40 | 14.40 | 0.488 | 0.566 |

1、版本记录

| DATE | REV. | DESCRIPTION |
|------------|------|----------------|
| 2020/04/19 | 1.0 | 首次发布 |
| 2023/07/10 | 1.1 | 优化延时、边沿时间及欠压保护 |
| 2023/10/25 | 1.2 | 增加内置二极管应用 |

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